





GRF4002W

RELEASE B DATA SHEET

Linear Driver: SDARS / Compensator / GPS 0.015 to 5.9 GHz

FEATURES

- Flexible Bias Voltage and Current
- Process: GaAs pHEMT
- \bullet Internally Matched to 50 Ω
- Compact 1.5 x 1.5 mm DFN-6 Package

AEC-Q100 Grade 2 Qualified

- 100% Device Reflow at Assembly
- 100% Optical Die Inspection

Reference: 5 V / 70 mA / 2.5 GHz

- Gain: 15 dB
- OIP3: 36.5 dBm
- OP1dB: 23.5 dBm
- Evaluation Board Noise Figure: 0.85 dB

APPLICATIONS

- SDARS LNA
- Cellular Repeaters (Compensator)
- GPS

ORDERING INFORMATION Buy it Now

M DESCRIPTION

The GRF4002W is a broadband low noise gain block designed for small cell, wireless infrastructure and other high performance applications. It exhibits outstanding broad-band noise figure (NF), linearity and return losses over 700 to 3800 MHz with a single match.

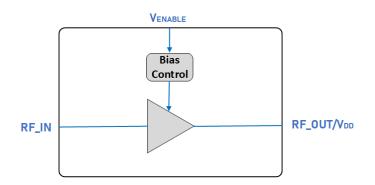
The device is operated from a supply voltage (V_{DD}) of 1.8 to 5 volts with a selectable I_{DDQ} range of 20 to 80 mA for optimal efficiency and linearity.

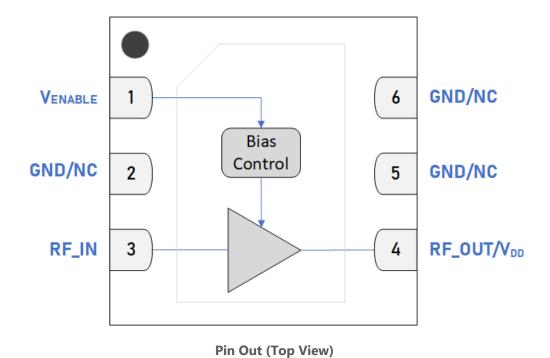
GRF4002W is internally matched to 50 Ω at the input and output ports needing only external DC blocks and a bias choke on the output.

Please consult with the GRF applications engineering team for custom tuning/evaluation board data. Packaged device S-Parameters are available on the website landing page.

Additional tunes can be found on the GRF4002W "Custom Tunes" product page: <u>GRF4002W Custom Tunes</u>

M BLOCK DIAGRAM





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Pin Assignments

Pin	Name	Description	Note
1	V _{ENABLE}	Enable Voltage Input	V_{ENABLE} and series resistor set I_{DDQ} . $V_{ENABLE} \le 0.2$ volts disables device. On die pull-down resistor will turn the device off if this node is allowed to float.
2, 5, 6	GND/NC	Ground or No Connect	No internal connection to die. We recommend connecting these pins to GND.
3	RF_IN	LNA RF Input	Internally matched to 50 Ω . An external DC blocking capacitor must be used.
4	RF_OUT/V _{DD}	LNA RF Output	Internally matched to 50 Ω . V_{DD} must be applied through a choke to this pin.
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



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Absolute Ratings

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{DD}	0	6	V
RF Input Power: Load VSWR < 2:1, V _{DD} = 5 V	P _{IN MAX}		22	dBm
Operating Temperature (package base)	T _{PKG BASE}	-40	105	°C
Maximum Channel Temperature (MTTF > 10 ⁶ hours)	T _{MAX}		170	°C
Maximum Dissipated Power	P _{DISS MAX}		500	mW

Electrostatic Discharge

Human Body Model	НВМ	250		V	
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Storage

Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	



Caution! ESD Sensitive Device.

Exceeding Absolute Maximum Rating conditions may cause permanent damage.

Note: For additional information, please refer to Manufacturing Note MN-001 - Packaging and Manufacturing Information.



All Guerrilla RF products are provided in RoHS compliant lead (Pb)-free packaging. For additional information, please refer to the Certificate of RoHS Compliance.



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Recommended Operating Conditions

Parameter	Symbol	Specification			Unit	Condition
raiameter	Symbol	Min.	Тур.	Max.	Offic	Condition
Supply Voltage	V _{DD}	1.8	5	6	V	
Operating Temperature Range	T _{PKG BASE}	-40		105	°C	
RF Frequency Range	F _{RF}	0.015	2.5	5.9	GHz	Typical Application Schematic with external matching components (notes 1 & 2).
RF_IN Port Impedance	Z _{RFIN}		50		Ω	
RF_OUT Port Impedance	Z _{RFOUT}		50		Ω	

Note 1: Operation outside of this range is supported by using different custom tunes. Examples of other optimized tunes can be found here: <u>GRF4002W Custom Tunes</u>

Note 2: Contact the Guerrilla RF Applications team for guidance on optimizing the tuning of the device for alternative bands.



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Nominal Operating Parameters - General

Parameter	Symbol	S	pecification		Unit	Condition	
raiameter	Symbol	Min.	Тур.	Max.	Onit	Condition	
Supply Current	I _{DD}		70		mA	V _{DD} = 5 V, V _{ENABLE} = 5 V.	
Enable Current	I _{ENABLE}		2.2	3	mA	$V_{DD} = 5 \text{ V}, V_{ENABLE} = 5 \text{ V}.$	
Switching Rise Time	T _{RISE}		500		ns	Gain mode to Disabled mode (note 3).	
Switching Fall Time	T _{FALL}		500		ns	Disabled mode to Gain mode (note 4).	

Disabled Mode

Leakage Current	I _{LEAKAGE}	1	5	μΑ	V _{DD} = 5 V, V _{ENABLE} = 0 V.

Thermal Data

Thermal Resistance (Infrared Scan) Θ_{JC} 131 °C/W board (note 5).

Note 3: Switching Time: 50% of V_{ENABLE} to 90% of P_{OUT}.

Note 4: Switching Time: 50% of V_{ENABLE} to 10% of P_{OUT}.

Note 5: MTTF > 10^6 hours for $T_i \le 170$ °C.



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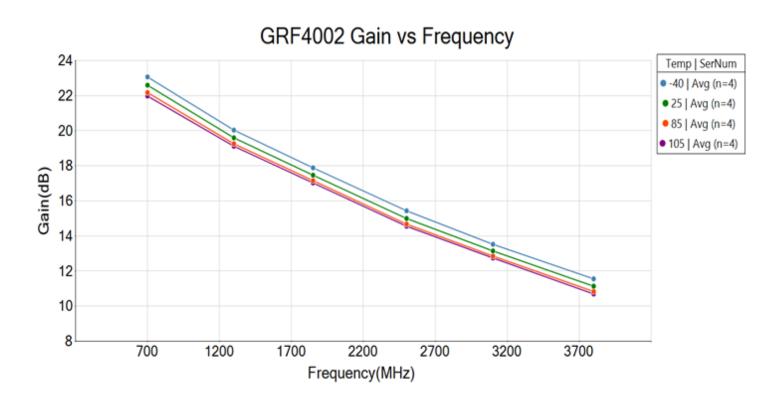
Nominal Operating Parameters - RF

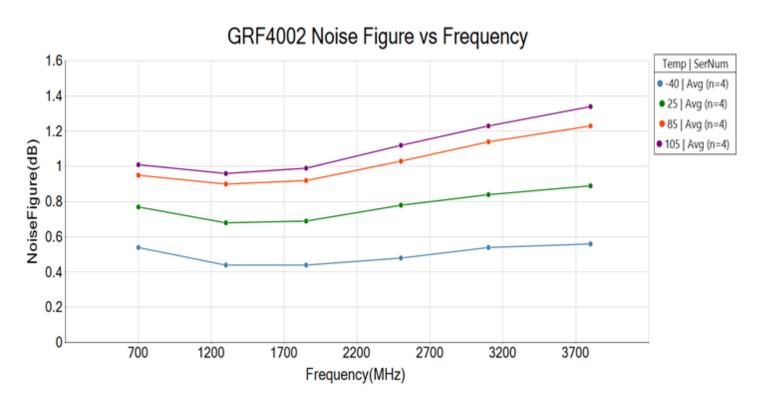
The following conditions apply unless noted otherwise; Typical Application Schematic, VDD = 5 V, 50Ω system impedance, $F_{TEST} = 2.5 \text{ GHz}$, $T_{PKG BASE} = 25 \text{ °C}$. Evaluation board losses are included within the specifications.

Parameter	Symbol	:	Specificatio	on	Unit	Condition
Parameter	Symbol	Min.	Тур.	Max.	Onic	Condition
Gain	S21	14	15		dB	
Reverse Isolation	S12		> 23		dB	SDARS Tune
Noise Figure	NF		0.85	1	dB	On standard evaluation board.
Output 3rd Order Intercept Point	OIP3		36.5		dBm	2 dBm P _{OUT} per tone. 2 MHz spacing (2499 and 2501 MHz).
Output 1 dB Compression Power	OP1dB	22	23.5		dBm	



GRF4002W Typical Operating Curves: 0.7 to 3.8 GHz

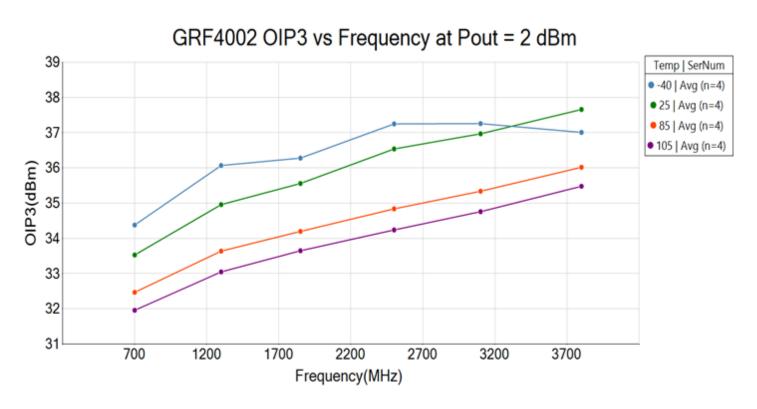






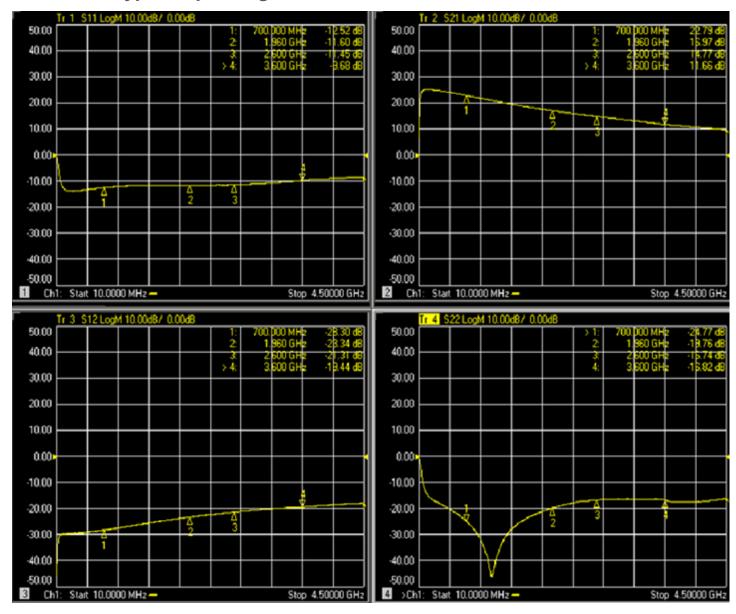
GRF4002W Typical Operating Curves: 0.7 to 3.8 GHz







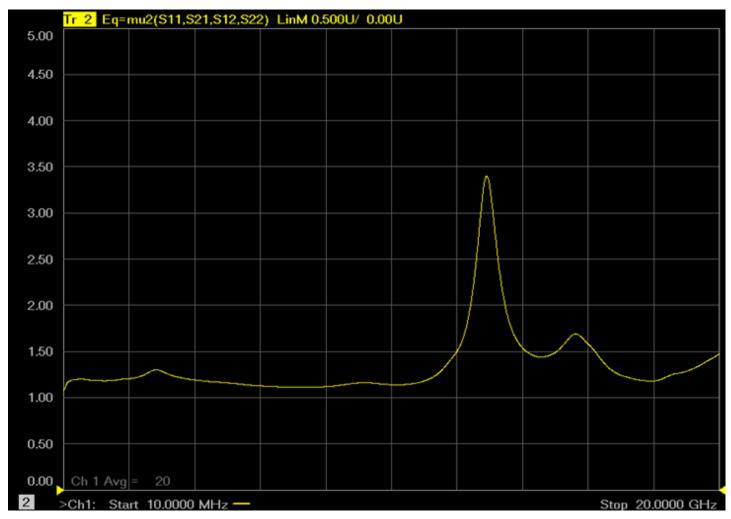
GRF4002W Typical Operating Curves: S-Parameters (0.7 to 3.8 GHz)





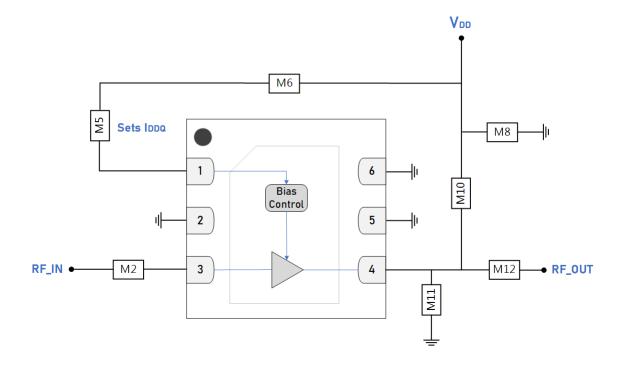
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GRF4002W Typical Operating Curves: Stability Mu Factor (10 MHz to 20 GHz)

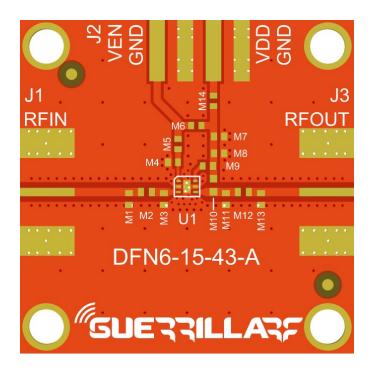


Note: $Mu \ge 1$ implies unconditional stability.





GRF4002W Standard Evaluation Board Schematic



GRF4002W Evaluation Board Assembly Diagram

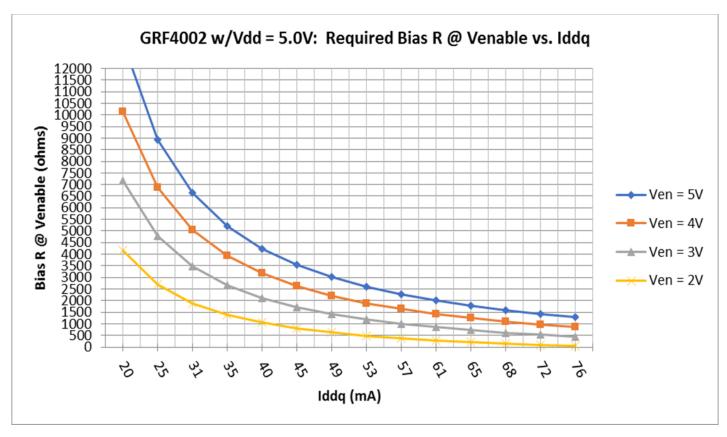




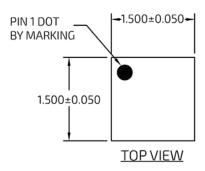
GRF4002W Evaluation Board Assembly Diagram Reference: 0.1 to 3.8 GHz Tune

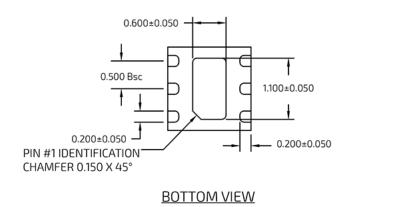
Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M2	Capacitor	Murata	GJM	100 pF	0402	ok
M5 (sets I _{DDQ})	Resistor	Various	5%	See Curves	0402	ok
M6	Resistor (jumper)	Various	5%	0 Ω	0402	ok
M8	Capacitor	Murata	GJM	0.1 μF	0402	ok
M10	Inductor	Coilcraft	HP	100 nH	0402	ok
M11	Capacitor	Murata	GJM	0.5 pF	0402	ok
M12	Capacitor	Murata	GJM	100 pF	0402	ok
Evaluation Board	DFN6-15-43-A					

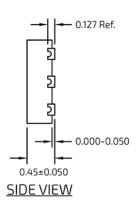
GRF4002W Bias Resistor Selection Curves





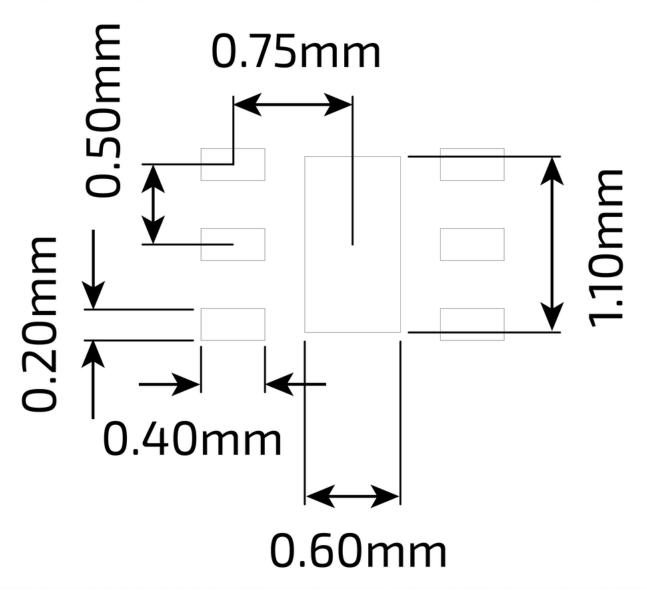






DFN 6 1.5x1.5mm Package Dimensions





DFN 6 1.5x1.5mm Suggested PCB Footprint (Top View)



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Package Marking Diagram

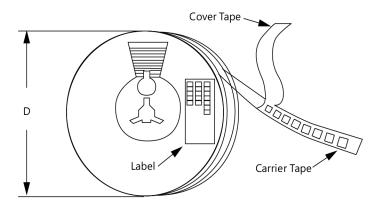


Line 1: "Y" = YEAR (single digit). "WW" = WORK WEEK and "w" = W for automotive.

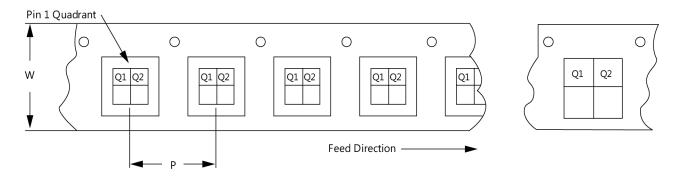
Line 2: "XXXX" = Device Part Number.

Tape and Reel Information

Guerrilla RF's tape and reel specification complies with Electronics Industries Association (EIA) standards for "Embossed Carrier Tape of Surface Mount Components for Automatic Handling" (reference EIA-481). Devices are loaded with pins down into the carrier pocket with protective cover tape and reeled onto a plastic reel. Each reel is packaged in a cardboard box. There are product labels on the reel, the protective ESD bag, and the outside surface of the box. For the latest reel specifications and package information (including units/reel), please visit Package Manufacturing Information | Guerrilla RF (guerrilla-rf.com).



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information



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Revision History

Revision Date	Description of Change
February 15, 2019	Release Ø Data Sheet.
June 1, 2022	Release A Data Sheet. Upgraded Data Sheet to new format.
August 4, 2023	Upgraded Data Sheet to newest format only.
September 12, 2023	Release B Data Sheet.
February 18, 2025	Added new evaluation board.
May 12, 2025	Extended frequency range from 100 - 3800 MHz to 15 - 5900 MHz.



RELEASE B DATA SHEET

Data Sheet Classifications

Data Sheet Status	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry-supplied transistor S-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements taken within the Guerrilla RF Applications Lab. Any MIN/MAX limits represented within the data sheet are based solely on <i>estimated</i> part-to-part variations and process spreads. All parametric values are subject to change pending the collection of additional data.
Release Ø	All data based on measurements taken with <i>production-released</i> material. TYP values are based on a combination of ATE and bench-level measurements, with MIN/MAX limits defined using <i>modelled estimates</i> that account for part-to-part variations and expected process spreads. Although unlikely, future refinements to the TYP/MIN/MAX values may be in order as multiple lots are processed through the factory.
Release A-Z	All data based on measurements taken with production-released material derived from multiple lots which have been fabricated over an extended period of time. MIN/MAX limits may be refined over previous releases as more statistically significant data is collected to account for process spreads.

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